

EE112 - Fall 2016 Analog Integrated Circuits I

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Discrete vs Integrated Circuits



Discrete Circuits

- Resistors and capacitors are frequently used
- AC coupled with coupling capacitors
- Large DC power supply voltage
- Transistor choice limited to available parts
- Mostly BJT, some MOS

IC

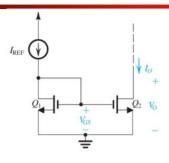
- Use mostly transistors
 - » Resistors and capacitors occupy too much areas
- Mostly DC coupled (without capacitors)
- Low DC power supply voltage (~ 1V)
- Can vary device size
- Predominantly CMOS» BiCMOS provides BJT

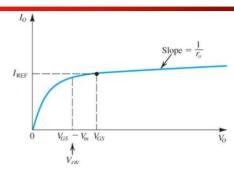
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Current Mirrors







- Neglecting channel length modulation
- If considering channel length modulation

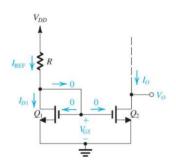
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Example Current Mirror with Reference Current Source

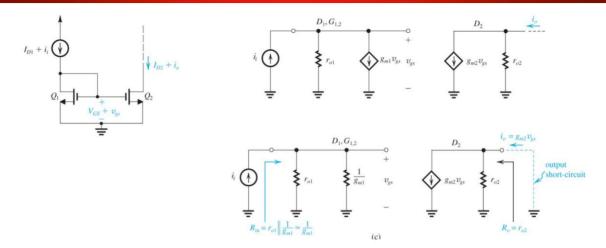


Neglecting channel length modulation



Small-Signal Model



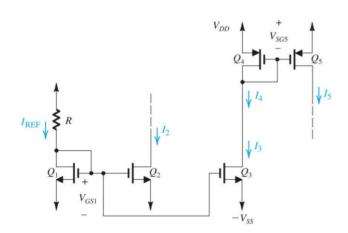


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MOS Current Steering Circuits





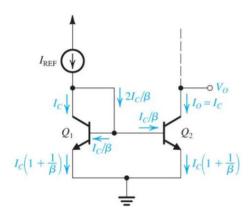
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BJT Current Mirror



Neglecting early effect

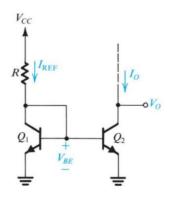


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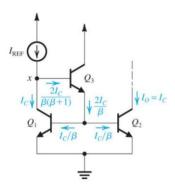
Example BJT Current Source





Current Mirror with Base Current Compensation



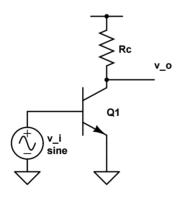


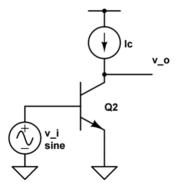
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Common-Emitter Amplifiers with Ideal Current Source Load



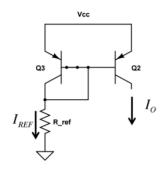


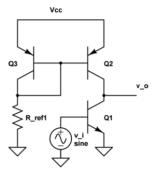


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CE Amplifier with Current Mirror Bias







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